Journal of Materials Chemistry C

Materials for optical, magnetic and electronic devices

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IN THIS ISSUE

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REVIEW

4966

Strategies for improving positive temperature effects in conductive polymer composites a review

Kui Liu, Zhuang Xu, Jing Mei, Jinlu Han, Fenghua Zheng, Hongqiang Wang, Youquo Huang, Qiang Wu, Guofeng Qin,* Juantao Jiang* and Qingyu Li*

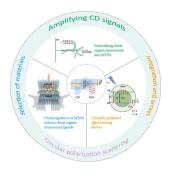


PERSPECTIVE

4993

Metal halide perovskites: promising materials toward next-generation circularly polarized luminescence

Bing Liang, Li Zhang, Yuanzhi Jiang, Siqi Chen and Mingjian Yuan*



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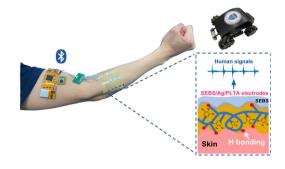


COMMUNICATIONS

5009

Screen printing of stretchable silver nanomaterial inks for a stable human-machine interface

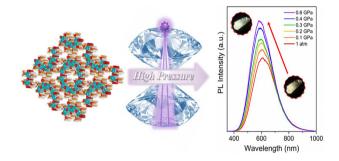
Yixuan Liu, Jianxiong Hao, Xinran Zheng, Chaoyang Shi* and Hui Yang*



5018

Tuning white light emission and band gap in the one-dimensional metal halide (C₆H₁₃N₄)₃Pb₂Br₇ by pressure engineering

Nan Li, Yuanyuan Fang, Long Zhang,* Kai Wang and Bo Zou*

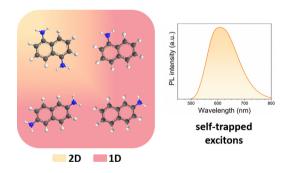


PAPERS

5024

Molecular engineering of naphthalene spacers in low-dimensional perovskites

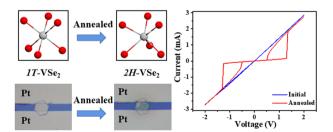
Andrei Mitrofanov, Yonder Berencén, Elaheh Sadrollahi, Regine Boldt, David Bodesheim, Hendrik Weiske, Fabian Paulus, Jochen Geck, Gianaurelio Cuniberti, Agnieszka Kuc* and Brigitte Voit*



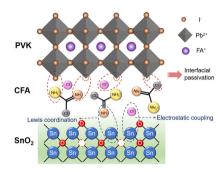
5032

Chemical-vapor-deposited 2D VSe₂ nanosheet with threshold switching behaviors for Boolean logic calculations and leaky integrate-and-fire functions

Lun Zhong, Wanxuan Xie, Jinxiang Yin and Wenjing Jie*



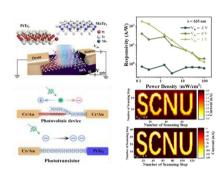
5039



Chloroformamidine hydrochloride as a molecular linker towards efficient and stable perovskite solar cells

Hui Li, Ping Fu, Ruixue Lu, Junxue Guo, Xin Guo, Rengui Li and Can Li*

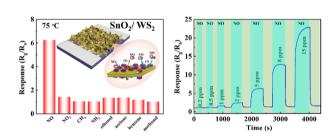
5045



Diverse modes regulated photoresponse and high-resolution imaging based on van der Waals semimetal PtTe₂/semiconductor MoTe₂ junctions

Ying Huang, He Yu, Wei Gao,* Peiting Wen, Zihao Liu, Hanyu Wang, Menglong Zhang* and Jingbo Li*

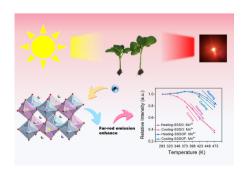
5056



Oxygen vacancy engineered tin dioxide/tungsten disulfide heterostructure construction for effective NO sensing

Baofeng Lv, Yongyong Pei, Shuo-En Wu, Tingting Xu,* Xiaowen Huang,* Yongtao Tian, Xinchang Wang, Longhui Zeng* and Xinjian Li

5064



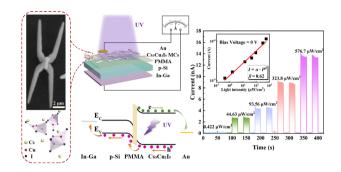
Flux induced highly efficient and stable phosphor Sr₂ScSbO₆:Mn⁴⁺ for plant growth lighting

Xue Meng, Zhijun Wang,* Zekang Yan, Dongxu Guo, Mengdi Liu, Jie Gong, Xiuxiu Feng, Ting Zhang, Xiaojie Li and Panlai Li*

5073

Enhanced self-powered UV photodetection from X chromosome-shaped Cs₃Cu₂I₅ microcrystals

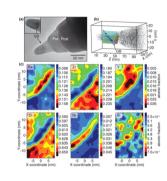
Xuesong Li, Yulu Zhou,* Fengchang Huang, Xiaoma Tao, Yifang Ouyang, Xiaoming Mo* and Jialong Zhao*



5082

Understanding the effects of fabrication process on $BaZr_{0.9}Y_{0.1}O_{3-\delta}$ grain-boundary chemistry using atom probe tomography

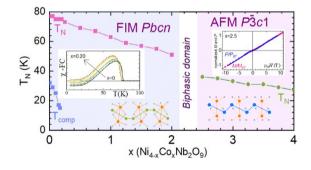
Daniel R. Clark.* David R. Diercks. Sandrine Ricote. Tania Tauer Dearden, Neal P. Sullivan, J. Will Medlin, Brian P. Gorman and Ryan P. O'Hayre*



5092

The $Ni_{4-x}Co_xNb_2O_9$ phase diagram: from magnetization reversal to linear magnetoelectricity

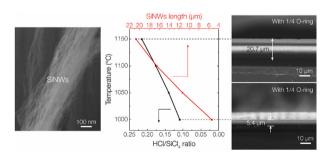
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- F. Damay and C. Martin*



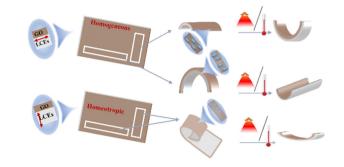
5102

Chemical vapor etching of silicon wafer for the synthesis of highly dense and aligned sub-5 nm silicon nanowire arrays

Sen Gao,* Juyeon Seo, Sanghyun Hong, Jianlin Li, Peiyun Feng, Ji Young Byun and Yung Joon Jung*



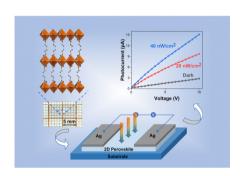
5110



Photothermal responsive composites of graphene oxide/liquid crystal networks with different mesogenic arrangements towards flexible and bionic devices

Ruicai Guo, Wenhui Gao, Xiaoshuai Li, Meishan Zhang, Hongmei Ma, Haifeng Yu and Yubao Sun*

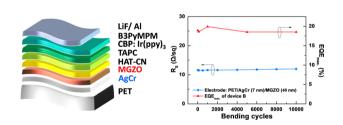
5116



Centimeter-size single crystals of 2D hybrid perovskites for shortwave light photodetection with a low detection limit

Chengshu Zhang, Hao Xiao, Qianwen Guan, Tingting Zhu, Lishan Liang, Ruiging Li, Huang Ye, Xinyi Niu and Junhua Luo*

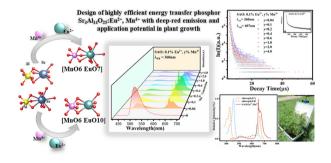
5123



A transparent composite electrode composed of AgCr and Mo-doped GaZnO to realize flexible bottom-emitting OLEDs

Meng-Hsuan Chiu, Dun-Cheng Huang, Cheng-Yung Ho, I-Hsuan Chuang, Yi-Ching Chen, Tzu-Hsin Hsiao and Chih-Hao Chang*

5135



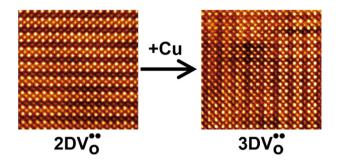
Design of highly efficient energy transfer phosphor Sr₄Al₁₄O₂₅:Eu²⁺,Mn⁴⁺ with deep-red emission and application potential in plant growth

Cancan Li, Yunpeng Zhou, Takatoshi Seto* and Yuhua Wang*

5147

Highly-conductive Cu-substituted brownmillerite with emergent 3-dimensional oxygen vacancy channels

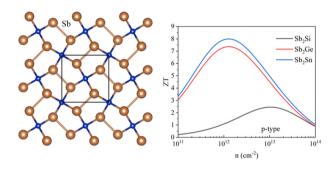
Wenqiao Han, Songbai Hu, Xiaowen Li, Qi Liu, Mao Ye, Zedong Xu, Sixia Hu, Yuanmin Zhu* and Lang Chen*



5156

Transport and thermoelectric properties of penta-Sb₂X monolayers

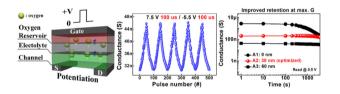
Nan Wu, Xiaofeng Fan,* David J. Singh and W. T. Zheng



5167

Role of the electrolyte layer in CMOS-compatible and oxide-based vertical three-terminal ECRAM

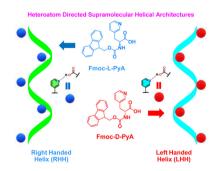
Geonhui Han, Jongseon Seo, Hyejin Kim and Deaseok Lee*



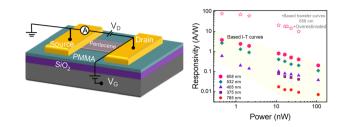
5174

Heteroatom-directed supramolecular helical-rich architectures in N-terminal protected pyridyl aromatic amino acids

Thangavel Vijayakanth, Bin Xue, Sarah Guerin, Sigal Rencus-Lazar, Natalia Fridman, Damien Thompson, Yi Cao and Ehud Gazit*



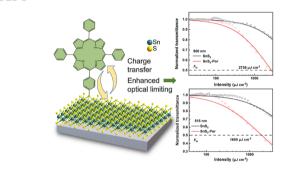
5182



Organic photodetectors based on pentacene single crystals with fast response and flexibility

Qiangian Du, Zhifeng Wang, Mengru Li, Yuguan Gan, Shuhong Li, Yunlong Liu, Wenjun Wang,* Fenggiu Wang and Shuchao Qin*

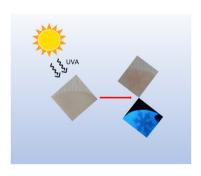
5190



Covalent functionalization of tin disulfide with porphyrin for ultrafast optical limiting

Zhiyuan Wei, Yan Fang, Hui Li, Zihao Guan, Naying Shan, Fang Liu, Yang Zhao, Lulu Fu, Zhipeng Huang, Mark G. Humphrey* and Chi Zhang*

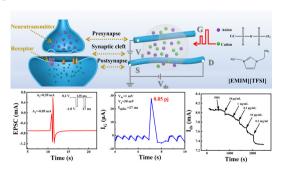
5199



Irradiation-responsive polysulfone film as a colorimetric UVA/UVB differentiator

Bernardo Monteiro, João Paulo Leal, Mani Outis, Maria Helena Casimiro and Cláudia C. L. Pereira*

5208



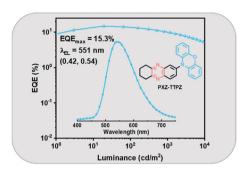
Boron nitride-mediated semiconductor nanonetwork for an ultralow-power fibrous synaptic transistor and C-reactive protein sensing

Mufang Li, Qing Shu, Xing Qing,* Jianmei Wu, Qing Xiao, Kangyu Jia, Xungai Wang and Dong Wang*

5217

Quinoxaline-based thermally activated delayed fluorescence emitters for highly efficient organic light-emitting diodes

Xiaoning Li, Yi Chen, Shuhui Li, Aisen Li, Liangjing Tu, Dongdong Zhang,* Lian Duan, Yujun Xie,* Ben Zhong Tang* and Zhen Li*



CORRECTION

5225

Correction: Photocatalytic removal of benzene over Ti₃C₂T_x MXene and TiO₂-MXene composite materials under solar and NIR irradiation

Sergii A. Sergiienko,* David M. Tobaldi,* Luc Lajaunie, Daniela V. Lopes, Gabriel Constantinescu, Aliaksandr L. Shaula, Nataliya D. Shcherban, Viacheslav I. Shkepu, José J. Calvino, Jorge R. Frade, João A. Labrincha and Andrei V. Kovalevsky